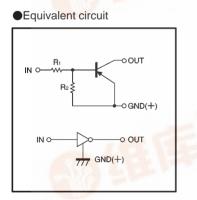
#### Transisto 查<sub>旬DTB123</sub>供应商

# Digital transistors (built-in resistors) DTB123YK / DTB123YC / DTB123YS

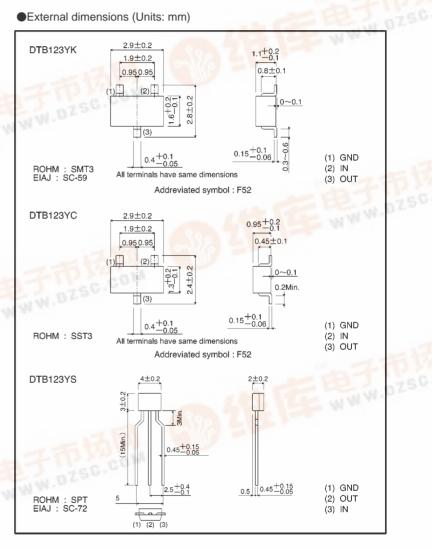
#### Features

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- The bias resistors consist of thinfilm resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- Only the on/off conditions need to be set for operation, making device design easy.

StructurePNP digital transistor(Built-in resistor type)







#### (96-302-B123Y)

## Transistors

# DTB123YK / DTB123YC / DTB123YS

## •Absolute maximum ratings (Ta = $25^{\circ}$ C)

Parameter	Symbol	Limits(DTB123Y			Unit
		К	С	S	Unit
Supply voltage	Vcc	-50			V
Input voltage	Vin	-12~+5			V
Output current	lc	-500			mA
Power dissipation	Pd	20	00	300	mW
Junction temperature	Tj	150			ĉ
Storage temperature	Tstg	-55~+150			C

## •Electrical characteristics (Ta = $25^{\circ}$ C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Input voltage	VI(off)	—	—	-0.3	v	Vcc=−5V, lo=−100 µ A	
	VI(on)	-2	—	—	v	Vo=-0.3V, Io=-20mA	
Output voltage	VO(on)	—	-0.1	-0.3	V	lo/l=-50mA/-2.5mA	
Input current	h	_	_	-3.6	mA	Vi=-5V	
Output current	IO(off)	—	—	-0.5	μA	Vcc=-50V, VI=0V	
DC current gain	Gi	56	_	_	_	Vo=-5V, lo=-50mA	
Input resistance	Rı	1.54	2.2	2.86	kΩ	—	
Resistance ratio	R2/R1	3.6	4.5	5.5	_	_	
Transition frequency	fт	—	200	—	MHz	Vce=-10V, le=5mA, f=100MHz *	

\* Transition frequency of the device

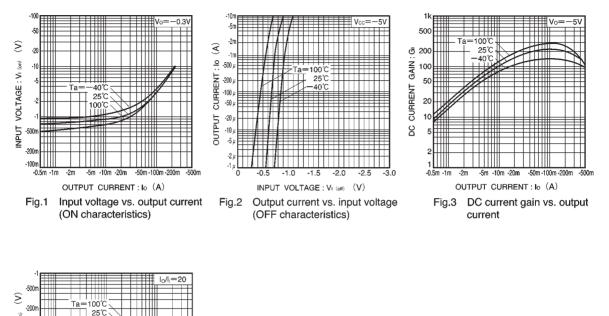
#### Packaging specifications

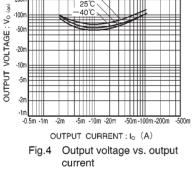
Package		SMT3	SST3	SPT
	Packaging type	Taping	Taping	Taping
	Code	T146	T116	TP
Part No.	Basic ordering unit (pieces)	3000	3000	5000
DTB123YK		0	_	_
DTB123YC		_	0	_
DTB123YS		—	—	0

# Transistors

# DTB123YK / DTB123YC / DTB123YS

#### Electrical characteristic curves





-40°C

-100

-50r

-20 -10r